



MJ P-Channel Enhancement Mode Power MOSFET

Description

The MJ20P09S uses advanced trench technology to provide excellent R_{DS(ON)}, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.

General Features

- VDS =-20V,ID =-9A
 RDS(ON) <28mΩ @ VGS=-4.5V
 RDS(ON) <40mΩ @ VGS=-2.5V
- High power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Schematic diagram

D1 D1 D2 D2 8 7 6 5 1 2 3 4 S1 G1 S2 G2

Marking and pin assignment

Application

Motor drive

Load switch

Power management



SOP-8 top view

ackage Marking	and Orderi	ng Information			
Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
MJ20P09S	MJ20P09S	SOP-8	Ø330mm	12mm	2500 units

Absolute Maximum Ratings (TA=25℃ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	-20	V
Gate-Source Voltage	Vgs	±12	V
Drain Current-Continuous	lD	-9	А
Drain Current -Pulsed (Note 1)	Ідм	-40	А
Maximum Power Dissipation	Po	3.1	W
Operating Junction and Storage Temperature Range	Тл,Тѕтс	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	Reja	42	°C/W	
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Electrical Characteristics (TA=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Uni
Off Characteristics		1	1			
Drain-Source Breakdown Voltage	BVDSS	V _{GS} =0V,I⊳=-250µA	-20	-	-	V
Zero Gate Voltage Drain Current	loss	VDS=-20V,VGS=0V	-	-	-1	μA
Gate-Body Leakage Current	lgss	VDS=±12V,VDS=0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	VGS(th)	Vos=Vgs,Io=-250µA	-0.5	-0.7	-1.4	V
Desir Course On Otata Desistance		V _{GS} =-4.5V, I _D =-6A	-	22	28	mΩ
Drain-Source On-State Resistance	Rds(on)	Vgs=-2.5V, Id=-5A		32	40	mΩ
Forward Transconductance	G FS	V _{DS} =-15V,I _D =-6A	-	17	-	S
Dynamic Characteristics (Note 4)						
Input Capacitance	Ciss		-	2100	-	PF
Output Capacitance	Coss	V _{DS} =-10V,V _{GS} =0V F=1.0MHz	-	498	-	PF
Reverse Transfer Capacitance	Crss	•	-	300	-	PF
Switching Characteristics (Note 4)		·				
Turn-on Delay Time	t _{d(on)}		-	25	-	nS
Turn-on Rise Time	tr	V _{DD} =-10V, RL=10Ω	-	30	-	nS
Turn-Off Delay Time	td(off)	Vgs=-4.5V,Rgen=6Ω	-	70	-	nS
Turn-Off Fall Time	tr		-	50	-	nS
Total Gate Charge	Qg		-	17		nC
Gate-Source Charge	Qgs	V _{DS} =-10V,I _D =-6A V _{GS} =-4.5V	-	4.1	_	nC
Gate-Drain Charge	Q _{gd}		-	4.3	-	nC
Drain-Source Diode Characteristics	I	1		1	L	<u> </u>
Diode Forward Voltage ^(Note 3)	Vsd	V _{GS} =0V,I _S =-9A	_	_	-1.2	v

Notes:

(1) Repetitive Rating: Pulse width limited by maximum junction temperature.

(2) Surface Mounted on FR4 Board, t \leq 10 sec.

(i) Pulse Test: Pulse Width \leq 300µs, Duty Cycle \leq 2%.

4 Guaranteed by design, not subject to production





Typical Electrical and Thermal Characteristics

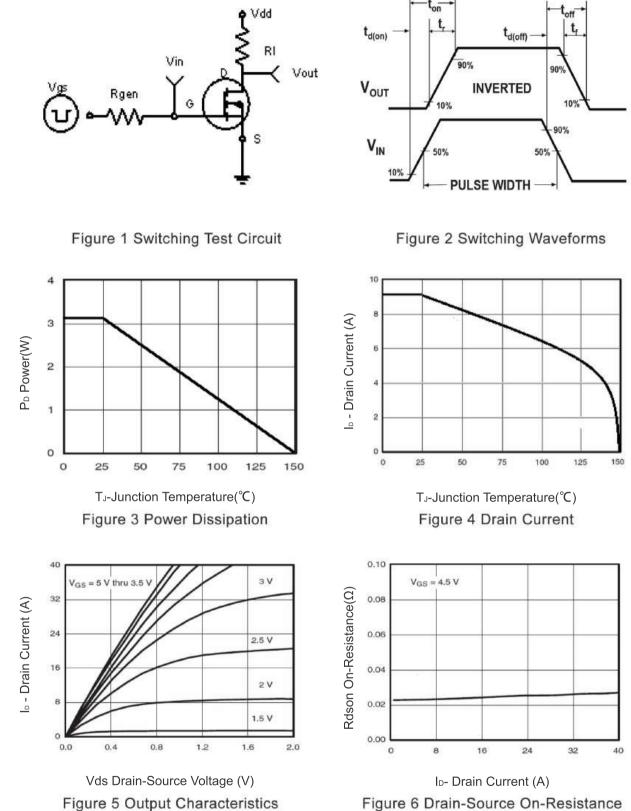
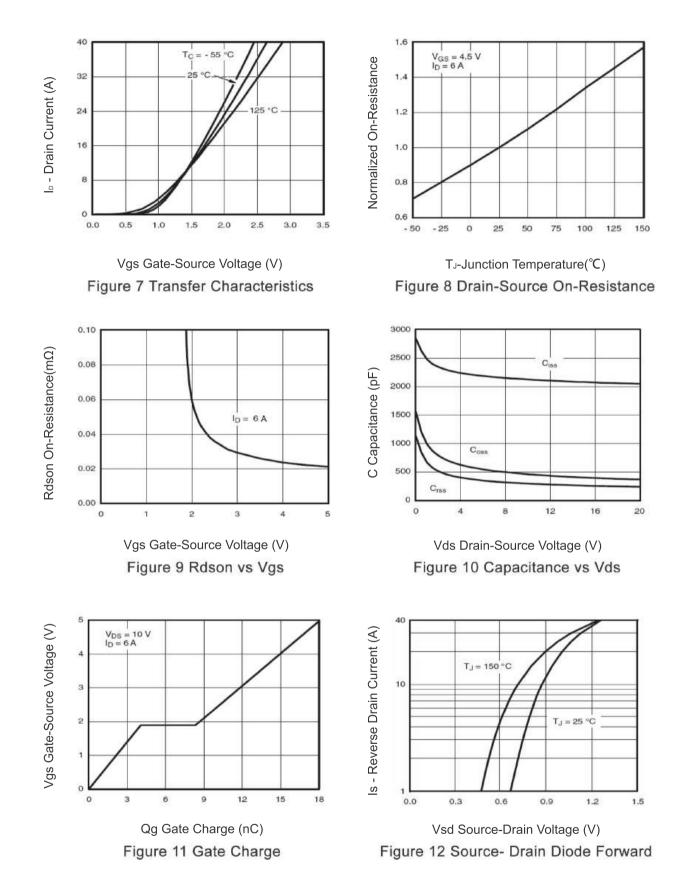


Figure 6 Drain-Source On-Resistance

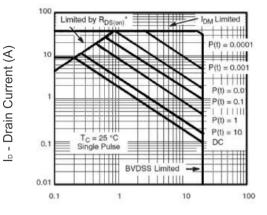




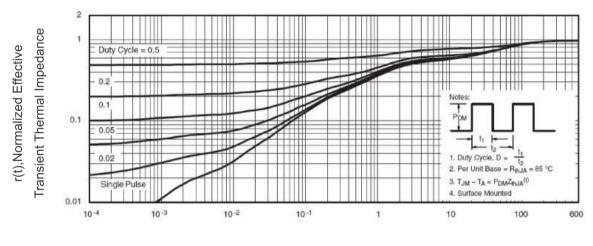








Vds Drain-Source Voltage (V) Figure 13 Safe Operation Area

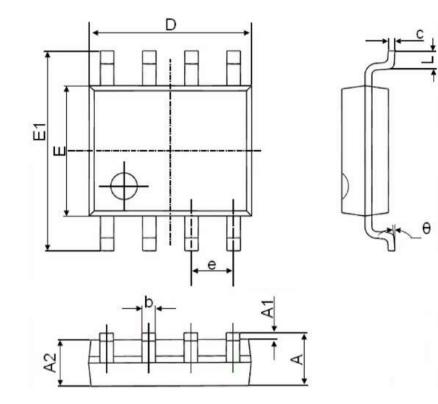


Square Wave Pluse Duration(sec) Figure 14 Normalized Maximum Transient Thermal Impedance





SOP-8 Package Information



Cumb al	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	1.350	1.750	0.053	0.069	
A1	0.100	0.250	0.004	0.010	
A2	1.350	1.550	0.053	0.061	
b	0.330	0.510	0.013	0.020	
с	0.170	0.250	0.006	0.010	
D	4.700	5.100	0.185	0.200	
E	3.800	4.000	0.150	0.157	
E1	5.800	6.200	0.228	0.244	
е	1.270	1.270(BSC)		(BSC)	
L	0.400	1.270	0.016	0.050	
θ	0°	8°	0°	8°	





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